Coherently coupled vertical-cavity surface-emitting laser arrays offer unique advantages for nonmechanical beam steering applications. We have applied dynamic coupled mode theory to show that the observed temporal phase shift between vertical-cavity surface-emitting array elements is caused by the detuning of their resonant wavelengths. Hence, a complete theoretical connection between the differential current injection into array elements and the beam steering direction has been established. It is found to be a fundamentally unique beam-steering mechanism with distinct advantages in efficiency, compactness, speed, and phase-sensitivity to current. Particularly applicable to miniature LADAR systems or high-speed, low-power-consumption optical communications. For example, typical modulation schemes require a differential voltage between 0.5 and 2 V, while the array shown herein can sweep its entire steering range with a differential voltage of only 100 mV. Similar arrays could thus be configured to steer on and off a receiver to achieve high-speed modulation with a low differential voltage.

The VCSEL wafer used for the arrays consists of a top p-type distributed Bragg reflector (DBR) mirror and an n-type bottom DBR on an n-type GaAs substrate. The active region located between the mirrors consists of quantum-wells emitting nominally at 980 nm. The fabrication process consists of standard photolithographic procedures. The photonic crystal hole pattern is designed to optically confine the mode within the cavities of the two array elements. The photonic crystal pattern and the mesa are formed by Freon reactive ion etching of a sacrificial SiO2 layer, and a subsequent inductively coupled plasma reactive-ion etch. Next, a high-energy (340 keV) proton implantation with a 1014 ions/cm2 dose is conducted with an 8 µm-thick photosresist blocking layer to provide current confinement within the array elements. Subsequently, bottom n-type contacts (AuGe-Ni-Au) and top p-type contacts (Ti-Au) are deposited using conventional electron-beam evaporation and a photosresist lift-off process. The etched region outside of the mesa is then planarized with a negative tone polyimide and cured at 365 °C. This polyimide...
layer allows electrical isolation of the large fan metal contacts (Ti-Au), which are deposited next by a photoreist lift-off process. Finally, a focused ion beam is used to etch a thin line down the array center to inhibit current flow between the elements in the highly conductive top layer, improving the current confinement between elements. A sketch and scanning electron microscope (SEM) image of the $2 \times 1$ VCSEL array are shown in Figures 2(a) and 2(b), respectively.

Dynamic coupled mode theory has previously been employed to explain dynamic instability in coupled edge-emitting laser arrays and phase tuning with injection-locked vertical-cavity laser arrays. Here it is examined to elucidate the phase shifting mechanism observed for a $2 \times 1$ VCSEL array operating in a coherently coupled state. The electric field of element $m$ is defined as $E_m = A_m e^{-i\Phi_m(t)}$, where $A_m$ is the field amplitude and $\Phi_m$ is the phase. The time change of the electric field under the influence of the field from neighboring elements, $E_{m-1}$ and $E_{m+1}$, can be found as:

$$\frac{dE_m}{dt} = \frac{1}{2} \left[ g(N_m - N_{th}) \right] (1 - iz)E_m + ik(E_{m+1} + E_{m-1})e^{-i\psi} + i(\omega_{\text{coupled}} - \omega_m)E_m,$$

(1)

where $g$ is the differential gain, $N$ is the carrier density, $N_{th}$ is the threshold carrier density, $z$ is the linewidth enhancement factor, $\kappa$ is the coupling strength between elements, $\Psi$ is the coupling phase ($\pi$ for an out-of-phase array), $\omega_{\text{coupled}}$ is the coupling frequency, and $\omega_m$ is the native resonant frequency of element $m$. This can then be transformed into the dimensionless equations:

$$\frac{dX_m}{dt} = \frac{Z_m X_m}{\tau_p} - \kappa \left( X_{m+1} \sin(\Phi_m - \Phi_{m+1} - \psi) + X_{m-1} \sin(\Phi_m - \Phi_{m-1} - \psi) \right),$$

(2)

and

$$\frac{d\Phi_m}{dt} = \frac{\alpha Z_m}{\tau_p} - \kappa \left[ \frac{X_{m+1}}{X_m} \cos(\Phi_m - \Phi_{m+1} - \psi) + \frac{X_{m-1}}{X_m} \cos(\Phi_m - \Phi_{m-1} - \psi) \right] + (\omega_{\text{coupled}} - \omega_m),$$

(3)

where $\tau_p$ is the photon lifetime, and $X_m$, $\Phi_m$, and $Z_m$ are the normalized magnitude, phase, and excess carrier density of element $m$. The following variables are used in the transformation:

$$X_m = \left( \frac{1}{2} g \tau_p \right)^{\frac{1}{2}} |E_m|$$

and

$$Z_m = \frac{1}{2} g N_{th} \tau_p \left( \frac{N_m}{N_{th}} - 1 \right),$$

(4)

where $\tau_p$ is the carrier lifetime. For a two-element array ($m = 1, 2$) in steady state, Eq. (3) can be reduced to

$$\alpha(Z_2 - Z_1) = \kappa \tau_p \left( \frac{X_1}{X_2} + \frac{X_2}{X_1} \right) \sin(\Phi_1 - \Phi_2 - \Psi) + (\omega_2 - \omega_1) \tau_p,$$

(5)

$Z_1$ and $Z_2$ can then be obtained from Eq. (2) and substituted into Eq. (5) to yield

$$\omega_2 - \omega_1 = -\kappa \left[ \alpha \left( \frac{X_1}{X_2} + \frac{X_2}{X_1} \right) \sin(\Phi_1 - \Phi_2 - \Psi) + \left( \frac{X_1}{X_2} + \frac{X_2}{X_1} \right) \cos(\Phi_1 - \Phi_2 - \Psi) \right].$$

(6)

The native resonant frequency difference between elements, found on the left side of Eq. (6), thus governs the phase shift between elements found on the right side of the equation, along with some additional correlations to other parameters. Equations (2) and (3) can also be manipulated to yield the native resonant frequencies of the individual elements as

$$\omega_1 = \omega_{\text{coupled}} - \kappa \frac{X_2}{X_1} \left[ \cos(\Phi_1 - \Phi_2 - \Psi) - \alpha \sin(\Phi_1 - \Phi_2 - \Psi) \right]$$

and

$$\omega_2 = \omega_{\text{coupled}} - \kappa \frac{X_1}{X_2} \left[ \cos(\Phi_1 - \Phi_2 - \Psi) + \alpha \sin(\Phi_1 - \Phi_2 - \Psi) \right].$$

(7)

Equations (6) and (7) are compared against measured values below.

Near- and far-field measurements are taken over the locking range of a $2 \times 1$ VCSEL array for a fixed current injection of 3.6 mA into the left element (element 1), and varying current injection into the right element (element 2). Current injection into the array elements is achieved with high-precision current sources attached to the sample via micro-positioned probes. The near-field intensity images are taken with a CMOS camera, 50× zoom near-IR lens, and 30 dB optical filter, as in Figure 3(a). The far-field profiles are obtained from an LD8900 goniometric radiometer as shown in Figure 3(b). This particular array is found to exhibit out-of-phase coupling, as portrayed by the sketch of the electric field profile in Figure 2(a). In this state we observe two near-field lobes separated by a null in between them, as in Figure 4(a). In the far-field, the distance from the...
source is several orders of magnitude larger than the element size, we similarly observe two lobes with an on-axis null in between them, as in Figure 4(c).

The near-field amplitude profiles were obtained as the square root of the measured intensity profiles after subtracting out the background noise. The near field was then separated into two apertures, as delineated by the red line in Figure 4(a). The near-field apertures are then propagated to the far field based on the Fraunhofer approximation. As discussed in Ref. 10, the relative phase of element 2, $\Phi_2$, is retrieved in an iterative process that continues until the relative amplitudes of the far-field lobes match those obtained experimentally. The coherence was similarly obtained by an iterative process matching the relative amplitude of the far-field minima. The propagated-fit and experimental far-field profiles are taken along the slices shown in Figures 4(b) and 4(c), respectively, and compared in Figure 4(d). High coherence between the array elements is evident by the far-field peaks and nulls that exist within the locking range of differential current injection. It can also be seen that as the current to element 2 is increased, the far field is pulled to the right, which is caused by an increasing relative phase lag in element 2.

The spatially resolved spectra of elements 1 and 2 are also obtained over the same current range. These measurements are obtained through a 62 $\mu$m fiber placed at the image plane of the VCSEL array. The separation between elements in the image plane of $\sim 300 \mu$m is sufficient to acquire spatially isolated data from each element. The objective lens, beam splitter, and fiber are moved in unison to collect the spectrum from each element. The spectral data from the left element, as shown in Figure 4(e), is offset by 0.05 nm to account for a slight change in the input power (IV characteristics) between measurements. It is seen from Figure 4(e) that only a single spectral peak is evident within the locking range. As the current to element 2 is increased further, the spectral line splits as the emission wavelength of element 2 increases to a greater extent than that of element 1. Further beyond the locking range, the elements are shown to lase almost completely independently at their respective resonant wavelengths.

Equation (6) provides the connection between the observed phase shifting and spectral splitting. The normalized fields $X_1$ and $X_2$ are determined as the total integrated amplitude measured in each near-field element. As can be seen from the near-field amplitude image in Figure 4(a), $X_1 > X_2$ at the given current difference. These amplitude values were obtained from each of the near field images corresponding to the varying current-injection values. The coupling strength is approximated from Eq. (6) as $\kappa = -\Delta \omega_{\text{max}} / 2x$, where $\Delta \omega_{\text{max}}$ is the maximum resonant frequency detuning within the locking range, outside of which spectral splitting is observed. The parameter $x$ is obtained from Ref. 11, and $\Delta \lambda_{\text{max}}$ is obtained as illustrated in Figure 5(a). These values lead to the $\kappa$ value given in Table I.

Within the locking range, $\lambda_{\text{coupled}}$ is observed, while $\lambda_1$ and $\lambda_2$ cannot be, by definition. In order to extract the phase based on Eq. (6), we have to first estimate how $\lambda_1$ and $\lambda_2$...
vary within the locking range. Since we have these values on both sides of the locking range, we can assume the native resonances vary linearly with current within the locking range. Given this assumption, the phase values retrieved from the propagated-fit method and from Eq. (6) are compared in Figure 5. The phase values are found to match well in this array and in arrays from an alternate sample operating at 850 nm, which serves to verify the correlation of Eq. (6).

The native resonant wavelengths can also be retrieved with Eq. (7) using the phase extracted from the propagated-fit method. Relatively linear progressions of the native resonance wavelengths across the locking range are thus shown in Figure 5. It is also noteworthy that $\lambda_{\text{coupled}}$ is found to reside closer to $\lambda_1$ because $X_1 > X_2$ across the locking range.

Previous work has shown how current injection alters the carrier and temperature distributions within the array elements, which in turn alters the refractive index profile. Dynamic testing has also shown that the relative phase shifting depends on this adjustment of the refractive index, although the correlation was yet unclear. Here we have employed dynamic coupled mode theory to complete the theoretical connection, as outlined in Figure 6. The index variation between elements adjusts their resonant wavelengths via $\Delta \lambda / \lambda \approx \Delta n_{\text{eff}} / n_{\text{eff}}$, and the resultant resonance detuning between elements causes the phase shift, per Eq. (6). The application of dynamic coupled mode theory thus elucidates the beam steering mechanism of coherently coupled VCSEL arrays. It is found to be a fundamentally unique beam-steering mechanism among those harnessed in alternate methods, and thus maintains unique advantages in efficiency, compactness, speed, and phase-sensitivity to current.

The parameters are shown in Table I.

![FIG. 5. Measured peak wavelength values and native resonances retrieved within the locking range. Propagated-fit phase measurements are also compared to that calculated from Eq. (6).](image)

![FIG. 6. Outline of progression from differential current injection to observed beam steering.](image)

<table>
<thead>
<tr>
<th>$\Psi$</th>
<th>$x$</th>
<th>$\Delta \lambda_{\text{max}}$ (nm)</th>
<th>$\Delta \nu_{\text{max}}$ (GHz)</th>
<th>$\kappa$ (GHz)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Pi$</td>
<td>$-5$</td>
<td>0.136</td>
<td>269</td>
<td>26.9</td>
</tr>
</tbody>
</table>